NSN 5962-01-369-6833

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View Online at https://aerobasegroup.com/nsn/5962-01-369-6833

Body Length:

1.060 inches

Body Width:

Between 0.220 inches and 0.310 inches

Body Height:

0.185 inches

Maximum Power Dissipation Rating:

1.1 watts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Bipolar and programmed and high impedance and w/enable and w/disable and electrostatic sensitive and w/clock

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

9 input

Case Outline Source And Designator:

D-8 mil-m-38510

Current Rating Per Characteristic:

90.00 milliamperes reverse current, dc absolute

Terminal Surface Treatment:

Solder

Product Name:

Registered and-or gate array

Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 12.0 volts power source

Memory Device Type:

Pal

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

20 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0

